



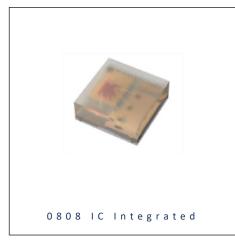
PRODUCT DATASHEET



- CHIP SMD with IC
- ▶ 0808 (2020) IC 0.75t
- ► Red/Green/Blue

N0M66S74IC





APPLICATIONS:

- Telecommunication
- Status Indicator
- Home Appliance
- Decoration Lighting
- Full Colour LED Strip
- Gaming Device
- Indoor Decorative Lighting

0808 IC-Integrated compliant

FEATURES:

- Package: CHIP EIA STD Package with Integrated IC Type 104
- Forward Current: 5mA
- Forward Voltage (typ.): +3.8~+5.5V
- Luminous Intensity (typ.): 425mcd mixed white
- Colour: Red/Green/Blue
- Dominant Wavelength (typ.): 622/527/467nm
- Viewing Angle: 120°
- Materials:
 - Resin: Epoxy (Water Diffused)
 - L/F Finish: Ag Plated
- Operating Temperature: -40~+85°C
- Storage Temperature: -40~+105°C
- IC Feature: Serial data transmission signal by single wire.
- Pixel: One pixel contains R, G, and B colour that each can achieve 256 level brightness grayscales, which forms 16,777,216 combination colours. Internal clock frequency operates at 800kHz.
- Soldering methods: IR Reflow soldering
- **Preconditioning:** acc. to JEDEC Level 3
- Packing: 8mm tape with Max.4000pcs/reel, ø180mm (7")



CHARACTERISTICS:

Absolute Maximum Characteristics (Ta=25°C)

Parameter	Symbol	Ratings	Unit
DC Forward Current	lf	5	mA
IC Power Supply Voltage	V _{DD}	+3.8~+5.5	V
IC Input Voltage	Vı	-0.4~V _{DD} +0.4	V
Operating Temperature	Topr	-40~+85	°C
Storage Temperature	Тѕтб	-40~+105	°C
Soldering Temperature	T _{SD}	260	°C

Electrical & Optical Characteristics (Ta=25°C, V_{DD}=5V)

Parameter		Symbol		Values	/alues		Test
Parameter			Min.	Тур.	Max.	Unit	Condition
Forward Voltage		VF	3.8	5	5.5	V	I⊧=5mA
	R		40	75	125		I⊧=5mA
Luminous Intensity	G	- Iv	135		390	mcd	
Luminous Intensity	В		25		100		
	W		325		550		
	R	λ _D	615		630	nm	I⊧=5mA
Dominant Wavelength	G		520		535		
	В		460		475		
Colour Coordinate	Х			0.2620			I₅=5mA
	Y			0.3130			IF-2ITIX
Viewing Angle		2 θ 1/2		120		deg	I⊧=5mA



Electrical & Optical Characteristics (Ta=25°C)

Daramatar	Symbol	Values			Unit	Test
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Static Current	Idd		0.3		mA	V _{DD} =4.5V I _{out} =OFF
Input Voltage Lovel	VIH	$0.7 V_{DD}$			V	D _{IN} , SET
Input Voltage Level	VIL			0.3 V _{DD}	V	Din, SET

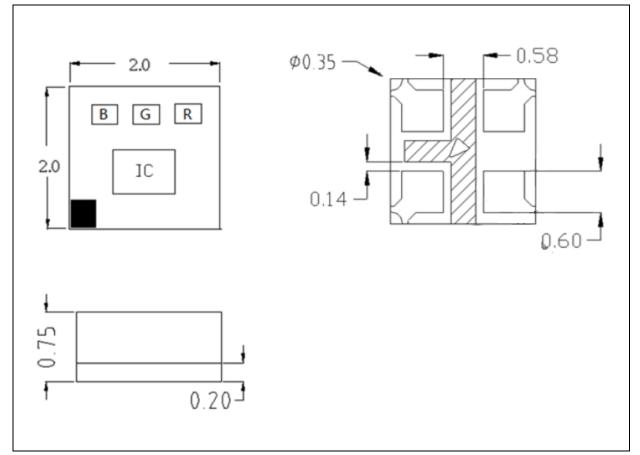
Switching Characteristics (Ta=25°C)

Parameter	Symbol	Values			Unit	Test
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Rate of Data Signal	Fdin		0.8		MHz	
Turn for Time	T _{PLH}			80	ns	
Transfer Time	TPHL			80	ns	Din → Dout
	Tr			50	ns	Ι _{ουτ} R/G/B=5mA
Conversion Time of IOUT R/G/B	T _f			100	ns	RL=400Ω CL=15pF



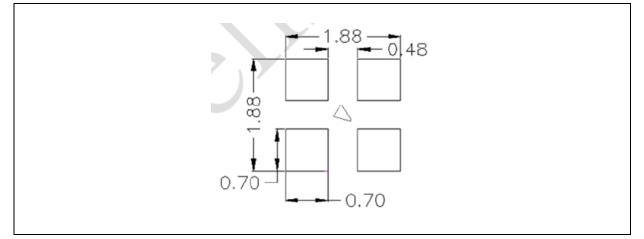
OUTLINE DIMENSION:

Package Dimension:



- 1. All dimensions are in millimetre (mm).
- 2. Tolerance ±0.2mm, unless otherwise noted.

Recommended Soldering Pad Dimension:



- 1. Dimensions are in millimetre (mm).
- 2. Tolerance ± 0.1 mm with angle tolerance $\pm 0.5^{\circ}$.

PIN CONFIGURATION:



	3 DOU	T B G R 2 VDD
	4 GND	
No.	Symbol	Function Description
No. 1	Symbol DIN	Function Description Control Data Signal Input
1	DIN	Control Data Signal Input



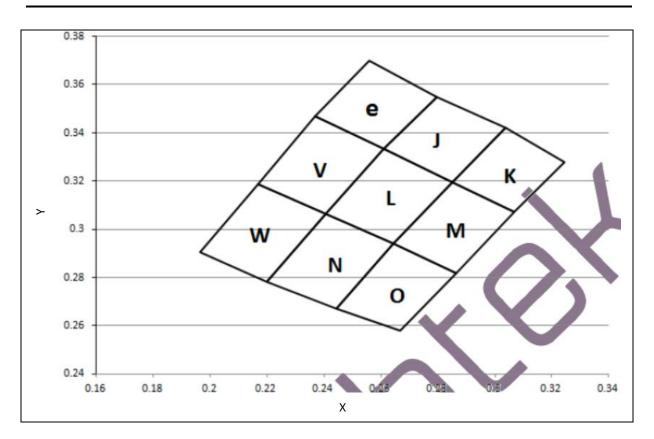
BINNING GROUPS:

Luminous Intensity Classifications (White) (I_F = 5mA, V_{DD}=5V):

Code	Min.	Max.	Unit
11	325	423	mad
12	423	550	mcd



CIE CHROMATICITY DIAGRAM:



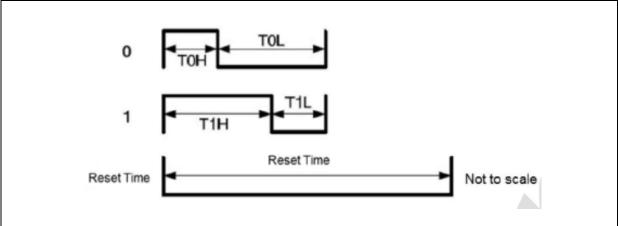
Chromaticity Coordinates Classifications (I_F = 5mA):

		1		2		3	2	1
	Х	Y	Х	Y	Х	Y	Х	Y
е	0.2369	0.3468	0.2609	0.3332	0.2797	0.3550	0.2559	0.3698
J	0.2609	0.3332	0.2797	0.3550	0.3036	0.3420	0.2849	0.3196
к	0.2851	0.3196	0.3036	0.3420	0.3243	0.3280	0.3068	0.3072
V	0.2169	0.3188	0.2369	0.3468	0.3609	0.3332	0.2406	0.3064
L	0.2406	0.3064	0.2609	0.3332	0.2849	0.3196	0.2643	0.2940
М	0.2643	0.2940	0.2849	0.3196	0.3068	0.3072	0.2865	0.2819
W	0.1963	0.2907	0.2169	0.3188	0.2406	0.3064	0.2200	0.2783
Ν	0.2200	0.2783	0.2406	0.3064	0.2643	0.2940	0.2444	0.2672
0	0.2444	0.2672	0.2643	0.2940	0.2865	0.2819	0.2667	0.2578



Function Description - Data Transfer Time (TH+TL=1.2µs±300ns):

1. Timing Wave Form:



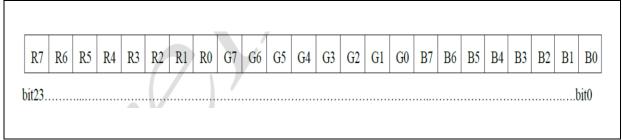
2. High Speed Mode:

Item	Description	Typical	Allowance
Тон	0 code, high voltage time	300ns	±150ns
T _{OL}	0 code, low voltage time	900ns	±150ns
T _{1H}	1 code, high voltage time	900ns	±150ns
T _{1L}	1 code, low voltage time	300ns	±150ns
RES	reset time	>200us	-

Note:

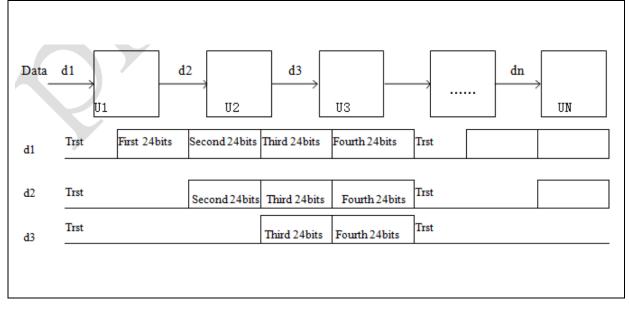
- 1. Luminous intensity is measured with a light sensor and filter combination that approximates the CIE eye response curve.
- 2. $\theta_{1/2}$ is the off-axis angle at which the luminous intensity is half the axial luminous intensity.
- 3. The dominant wavelength λ_D is derived from CIE chromaticity diagram and represents the single wavelength which defines the colour of the device. Peak emission wavelength tolerance is ±1nm.

3. Composition of 24 Bit Data:



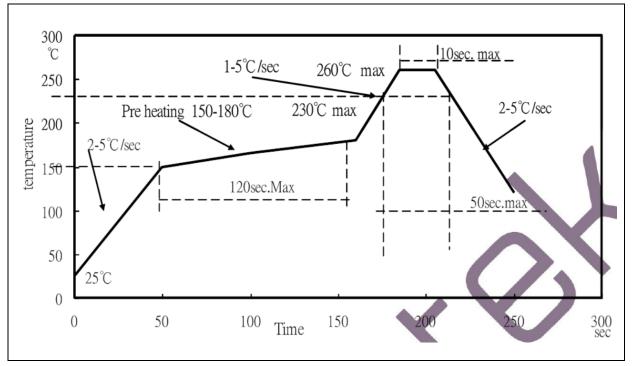


4. Data Transmission Method:





RECOMMENDED SOLDERING PROFILE:



Lead-free Solder IR Reflow:

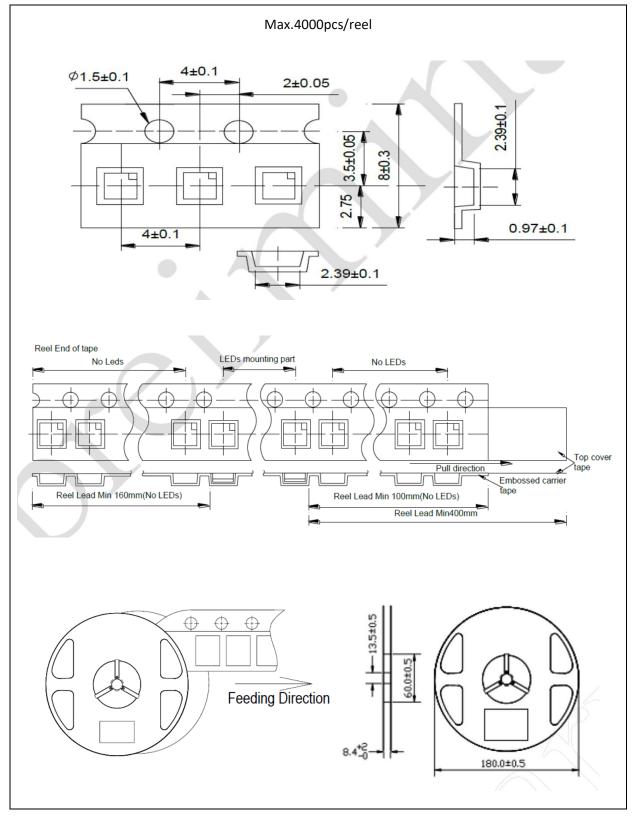
Note:

- 1. We recommend the reflow temperature 240°C (±5°C). The maximum soldering temperature should be limited to 260°C.
- 2. Maxima reflow soldering: 1 time.
- 3. Before, during, and after soldering, should not apply stress on the components and PCB board.



PACKING SPECIFICATION:

Reel Dimension:



PRECAUTIONS OF USE:



Storage:

It is recommended to store the products in the following conditions:

- Humidity: 60% R.H. Max.
- Temperature: 5°C~30°C (41°F ~86°F).

Shelf life in sealed bag: 12 months at 5°C~30°C and <60% R.H.

Once the package is opened, the products should be used within 24 hours. Otherwise, they should be kept in a damp-proof box with descanting agent stored at R.H.<20% and apply baking before use.

Over-Current Proof:

Must apply resistors for protection otherwise slight voltage shift will cause big current change and burnout will happen.

Baking:

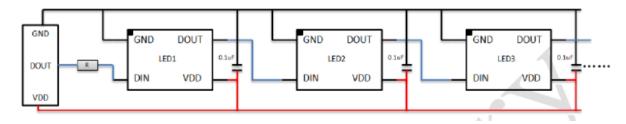
It is recommended to bake the LED before soldering if the pack has been unsealed for longer than 24hrs. The suggested baking conditions are as followings:

60±3°C x 6hrs and <5%RH, taped / reel package.

It's normal to see slight color fading of carrier (light yellow) after baking in process.

Testing Circuit:

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When the first LED is connected to the MCU, a resistance R is needed in series between its signal input line and the MCU. The size of R depends on the number of cascade beads. The more cascades, the smaller resistance R is used. It is generally recommended that the value be between 100-1K. Usually the recommended value is around 300 R. In order to make the LEDs work more stably, a parallel capacitor is needed between VDD and GND of each.

Cleaning:

Use alcohol-based cleaning solvents such as isopropyl alcohol to clean the LED carrier / package. Avoid putting any stress force directly on to the LED lens.

ESD (Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing the LED all time. All devices, equipment, machinery, work tables, and storage racks must be properly grounded.



REVISION RECORD:

Version	Date	Summary of Revision
A1.0	10/07/2024	Datasheet set-up.